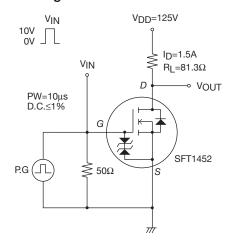
#### Electrical Characteristics at Ta=25°C

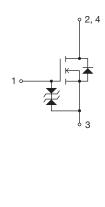
| Parameter                                  | Symbol               | Conditions  | Ratings |      |     | Unit |
|--|----------------------|---|---------|------|-----|------|
|  |                      | Conditions  | min     | typ  | max | Onit |
| Drain-to-Source Breakdown Voltage          | V(BR)DSS             | I <sub>D</sub> =1mA, V <sub>GS</sub> =0V                        | 250     |      |     | V    |
| Zero-Gate Voltage Drain Current            | IDSS                 | V <sub>DS</sub> =250V, V <sub>GS</sub> =0V                      |         |      | 1   | μΑ   |
| Gate-to-Source Leakage Current             | IGSS                 | VGS=±24V, VDS=0V  |         |      | ±10 | μΑ   |
| Gate Threshold Voltage                     | V <sub>GS</sub> (th) | V <sub>DS</sub> =10V, I <sub>D</sub> =1mA                       |         |      | 4.5 | V    |
| Forward Transconductance                   | 9 <sub>FS</sub>      | V <sub>DS</sub> =10V, I <sub>D</sub> =1.5A                      |         | 1.7  |     | S    |
| Static Drain-to-Source On-State Resistance | R <sub>DS</sub> (on) | I <sub>D</sub> =1.5A, V <sub>GS</sub> =10V                      |         | 1.8  | 2.4 | Ω    |
| Input Capacitance                          | Ciss                 |   |         | 210  |     | pF   |
| Output Capacitance                         | Coss                 | V <sub>DS</sub> =20V, f=1MHz                                    |         | 20   |     | pF   |
| Reverse Transfer Capacitance               | Crss                 |   |         | 7    |     | pF   |
| Turn-ON Delay Time                         | t <sub>d</sub> (on)  |   |         | 8    |     | ns   |
| Rise Time                                  | tr                   | See specified Test Circuit.                                     |         | 9    |     | ns   |
| Turn-OFF Delay Time                        | t <sub>d</sub> (off) |   |         | 13   |     | ns   |
| Fall Time                                  | tf                   |   |         | 14   |     | ns   |
| Total Gate Charge                          | Qg                   |   |         | 4.2  |     | nC   |
| Gate-to-Source Charge                      | Qgs                  | V <sub>DS</sub> =125V, V <sub>GS</sub> =10V, I <sub>D</sub> =3A |         | 1.4  |     | nC   |
| Gate-to-Drain "Miller" Charge              | Qgd                  |   |         | 1.0  |     | nC   |
| Forward Diode Voltage                      | V <sub>SD</sub>      | I <sub>S</sub> =3A, V <sub>GS</sub> =0V                         |         | 0.95 | 1.2 | V    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **Switching Time Test Circuit**



#### **Electrical Connection**

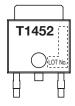


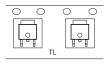
## **Ordering & Package Information**

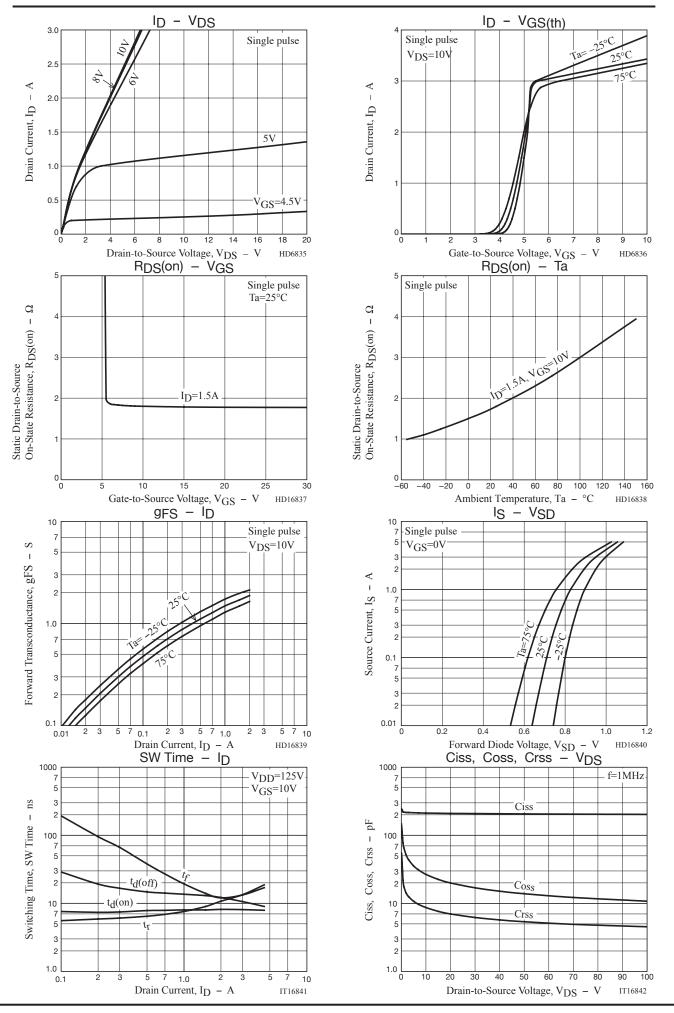
| Device       | Package              | Shipping     | memo                       |  |
|--------------|----------------------|--------------|----------------------------|--|
| SFT1452-H    | IPAK(TP) 500pcs./bag |              |                            |  |
| SFT1452-W    | SC-64, TO-251        | 500pcs./bag  | - Pb-Free and Halogen Free |  |
| SFT1452-TL-H | DAPK(TP-FA)          | 700000 /2001 |                            |  |
| SFT1452-TL-W | SC-63, TO-252        | 700pcs./reel |                            |  |

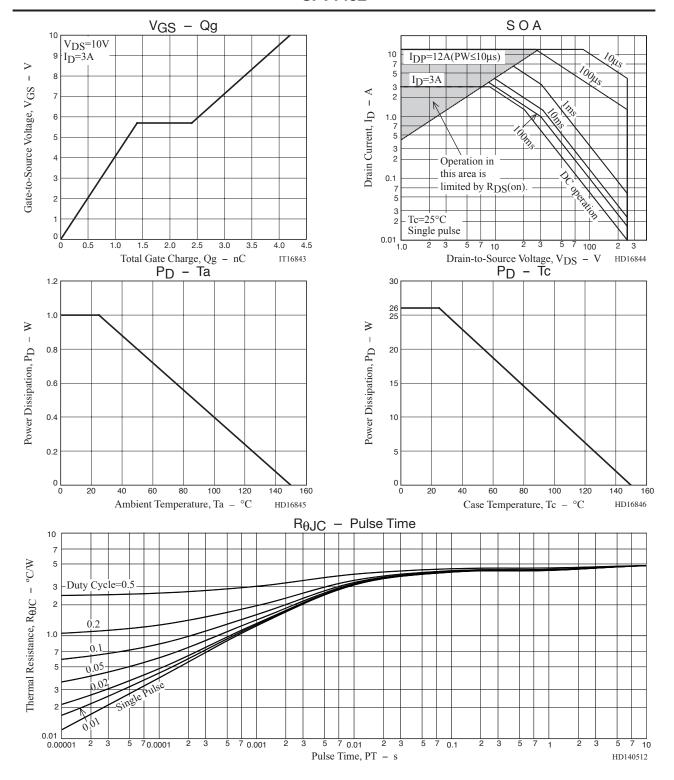
# Marking

## Packing Type:TL







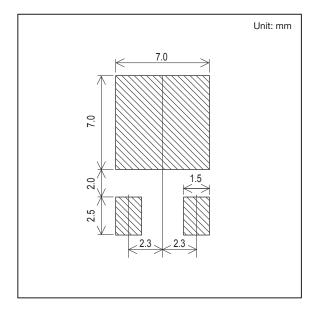


## **Outline Drawing**

SFT1452-TL-H, SFT1452-TL-W

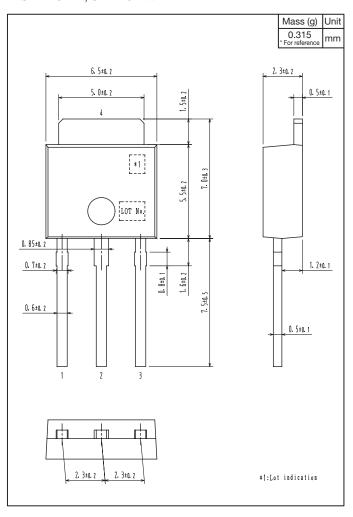
# Mass (g) Unit 0.282 \* For reference mm 6. 5±0. 2 2. 3±0.2 5. O±0. 2 0. 5±0. 1 1. 5±0. 2 [\*1] 7.0±0.3 5. 5±0. 2 LOT No. 0. 5±0. 15 1. 2±0. 3 0. 85±0. 2 2, 5±0.3 0. 7±0.2 2 3 1. 2±0.3 0. 6±0.2 0~0.2 2. 3±0. 2 2. 3±0.2 Pin 2 is idle pin with electrical designation only carried. \*1:Lot indication

## **Land Pattern Example**



#### **Outline Drawing**

SFT1452-H, SFT1452-W



Note on usage: Since the SFT1452 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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